TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

2SC5086FT

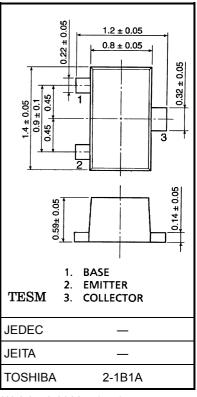
VHF~UHF Band Low Noise Amplifier Applications

Unit: mm

- Low noise figure, high gain.
- NF = 1.1dB, $|S_{21e}|^2 = 11dB$ (f = 1 GHz)

Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|-----------------------------|------------------|----------------|------|
| Collector-base voltage | V_{CBO} | 20 | V |
| Collector-emitter voltage | V _{CEO} | 12 | V |
| Emitter-base voltage | V _{EBO} | 3 | ٧ |
| Base current | Ι _Β | 40 | mA |
| Collector current | I _C | 80 | mA |
| Collector power dissipation | PC | 100 | mW |
| Junction temperature | Tj | 125 | °C |
| Storage temperature range | T _{stg} | −55~125 | °C |



Weight: 0.0022 g (typ.)

Microwave Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------------------|-------------------------------------|--|-----|------|-----|------|
| Transition frequency | f _T | $V_{CE} = 10 \text{ V}, I_{C} = 20 \text{ mA}$ | 5 | 7 | _ | GHz |
| Insertion gain | S _{21e} ² (1) | V _{CE} = 10 V, I _C = 20 mA, f = 500 MHz | _ | 16.5 | _ | - dB |
| | S _{21e} ² (2) | V _{CE} = 10 V, I _C = 20 mA, f = 1 GHz | 7.5 | 11 | _ | |
| Noise figure | NF (1) | $V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}, f = 500 \text{ MHz}$ | | 1 | | - dB |
| | NF (2) | $V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}, f = 1 \text{ GHz}$ | | 1.1 | 2 | |

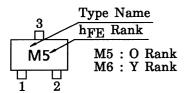
Electrical Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|------------------------------|-----------------------------|--|-----|------|------|------|
| Collector cut-off current | I _{CBO} | $V_{CB} = 10 \text{ V}, I_{E} = 0$ | _ | _ | 1 | μА |
| Emitter cut-off current | I _{EBO} | V _{EB} = 1 V, I _C = 0 | _ | _ | 1 | μА |
| DC current gain | h _{FE} (Note 1) | V _{CE} = 10 V, I _C = 20 mA | 80 | _ | 240 | |
| Output capacitance | C _{ob} | V _{CB} = 10 V, I _E = 0, f = 1 MHz (Note 2) | _ | 1.0 | _ | pF |
| Reverse transfer capacitance | C _{re} | | _ | 0.65 | 1.15 | pF |

Note 1: hFE classification O: 80~160, Y: 120~240

Note 2: C_{re} is measured by 3 terminal method with capacitance bridge.

Marking



2 2003-08-08

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